

MILITARY SPECIFICATION

Inactive for new design as of 24 July 1995
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MICROCIRCUITS, DIGITAL, 4096-BIT SCHOTTKY, BIPOLAR,
 PROGRAMMABLE READ-ONLY MEMORY (PROM), MONOLITHIC SILICON

This amendment forms a part of MIL-M-38510/206C, dated
 10 September 1986, and is approved for use by all Departments
 and Agencies of the Department of Defense.

PAGE 1

Add case outline "U" to paragraph 1.2.3 to read as follows:

1.2.3 Case outlines. The case outlines are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
E	GDIP1-T16 or CDIP2-T16	16	dual-in-line
F	GDFP2-F16 or CDFP3-F16	16	flat pack
V	GDIP1-T18 or CDIP2-T18	18	dual-in-line
Y	See figure 1	24	square chip carrier
Z	See figure 1	18	flat pack
U	GDFP2-F18	18	flat pack

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Paragraph 1.3, Absolute maximum ratings, change Thermal resistance to read as follows:

Thermal resistance, junction-to-case (θ_{JC}) 1/:
 Cases E, F, V, and U ----- See MIL-STD-1835

PAGE 3

Change paragraph 3.2.4 to read as follows:

3.2.4 Case outlines. The case outlines shall be in accordance with MIL-STD-1835 and 1.2.3 herein.

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For FIGURE 2. Terminal connections, under Device types 01, 02 and 04 change as follows:

Delete Cases V and Z and replace with Case V, Z and U

MIL-M-38510/206C
AMENDMENT 1

CONCLUDING MATERIAL

Custodians:
Army - CR
Navy - EC
Air Force - 11

Review activities:
Army - AR, MI, SM
Navy - AS, SH, CG, MC
Air Force - 19, 99

Preparing activity:
DLA-CC

(Project 5962-1866)